

# Abstracts

## A Power Amplifier Based on an Extended Resonance Technique

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*A. Martin, A. Mortazawi and B.C. De Loach, Jr.. "A Power Amplifier Based on an Extended Resonance Technique." 1995 *Microwave and Guided Wave Letters* 5.10 (Oct. 1995 [MGWL]): 329-331.*

A new power amplifier based on an extended resonance technique is presented. This technique produces high power through multiplying the power handling capability of a single device by the number of devices employed while maintaining the gain of a single-device amplifier. An X-band power combining amplifier employing four 100 mW MESFET's was designed and constructed. The small signal gain was measured at 11.5 dB, and a maximum of 480 mW was obtained at 9.57 GHz with a power-added efficiency of 30.8%.

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